

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



MOS



LDO



Diode



Sensor



DC-DC

Product Specification

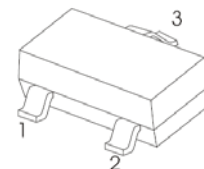
▶ Domestic	Part Number	SI2312A
▶ Overseas	Part Number	SI2312A
▶ Equivalent	Part Number	SI2312A

EV is the abbreviation of name EVVO

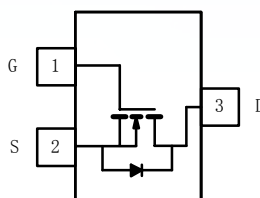
■ Features

- $V_{DS} (V) = 20V$
- $I_D = 6 A (V_{GS} = 4.5V)$
- $R_{DS(ON)} < 26m\Omega (V_{GS} = 4.5V)$
- $R_{DS(ON)} < 33m\Omega (V_{GS} = 2.5V)$
- $R_{DS(ON)} < 50m\Omega (V_{GS} = 1.8V)$

SOT - 23



1. GATE
2. SOURCE
3. DRAIN



■ Absolute Maximum Ratings $T_a = 25^\circ C$

Parameter		Symbol	5 sec	Steady State	Unit
Drain-Source Voltage		V _{DS}	20		V
Gate-Source Voltage		V _{GS}	±8		
Continuous Drain Current *1	Ta=25℃	I _D	6	5	A
	Ta=70℃		5	4	
Pulsed Drain Current *2		I _{DM}	15		
Avalanche Current *2	L=0.1mH	I _{AS}	15		
Single Avalanche Energy		E _{AS}	11.25		mJ
Power Dissipation *1	Ta=25℃	P _D	1.25	0.75	W
	Ta=70℃		0.8	0.48	
Thermal Resistance.Junction- to-Ambient *1 t≤5 sec Steady State		R _{thJA}	100		℃/W
			166		
Thermal Resistance.Junction-to-Foot		R _{thJF}	50		
Junction Temperature		T _J	150		℃
Storage Temperature Range		T _{stg}	-55 to 150		

*1 Surface Mounted on 1" x 1" FR4 Board.

*2 Pulse width limited by maximum junction temperature

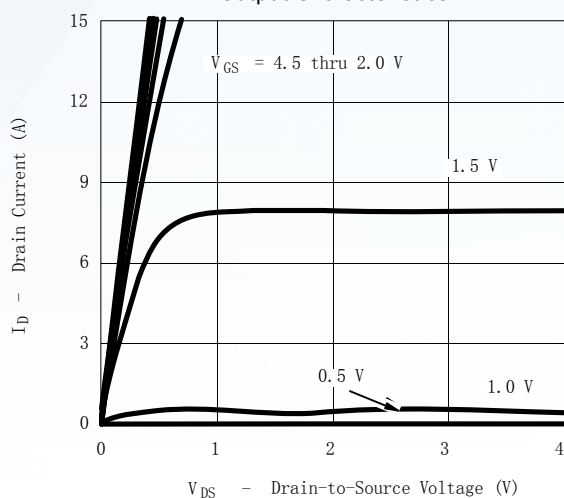
■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	V _{DSS}	I _D =250 μA, V _{GS} =0V	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V			1	μA
		V _{DS} =20V, V _{GS} =0V, Ta=70°C			75	
Gate-Body Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250 μA	0.45	0.65	0.85	V
On-State Drain Current *1	I _{D(on)}	V _{DS} ≥ 10 V, V _{GS} = 4.5 V	15			A
Static Drain-Source On-Resistance *1	R _{DS(on)}	V _{GS} =4.5V, I _D =5.0A			26	mΩ
		V _{GS} =2.5V, I _D =4.5A			33	
		V _{GS} =1.8V, I _D =4.0A			50	
Forward Transconductance *1	g _{FS}	V _{DS} =15V, I _D =5.0A		40		S
Total Gate Charge	Q _g	V _{GS} =4.5V, V _{DS} =10V, I _D =5.0A		11.2	14	nC
Gate Source Charge	Q _{gs}			1.4		
Gate Drain Charge	Q _{gd}			2.2		
Turn-On DelayTime	t _{d(on)}	I _D =1.0A, V _{DS} =10V, V _{GEN} =4.5V R _L =10Ω, R _G =6Ω		15	25	ns
Turn-On Rise Time	t _r			40	60	
Turn-Off DelayTime	t _{d(off)}			48	70	
Turn-Off Fall Time	t _f			31	45	
Body Diode Reverse Recovery Time	t _{rr}	I _F = 1.0A, di/dt= 100A/μs		13	25	
Maximum Body-Diode Continuous Current	I _S				1.0	A
Diode Forward Voltage	V _{SD}	I _S =1.0A, V _{GS} =0V		0.8	1.2	V

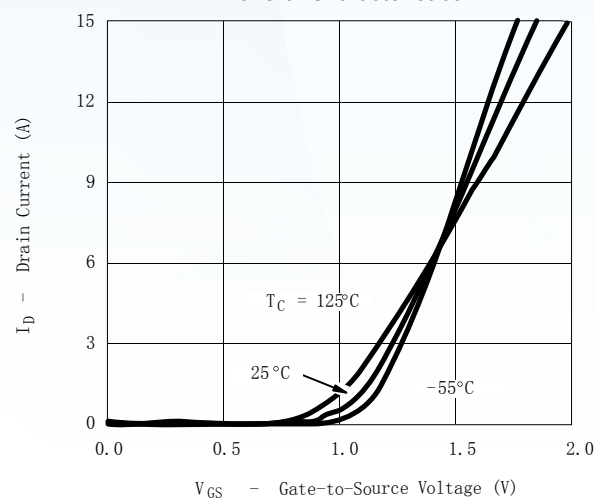
*1 Pulse test: PW ≤ 300us duty cycle ≤ 2%.

Typical Characteristics

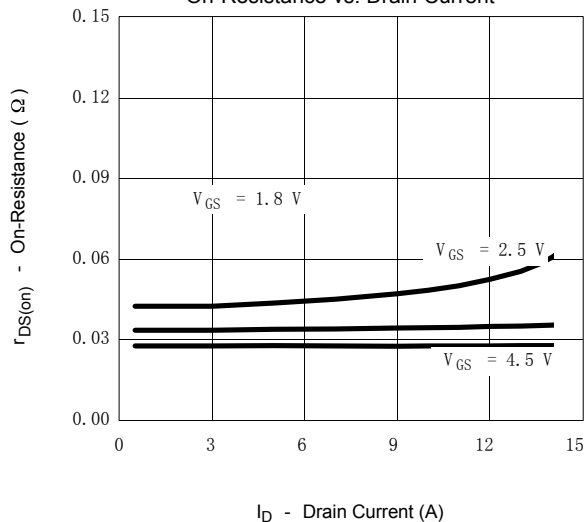
Output Characteristics



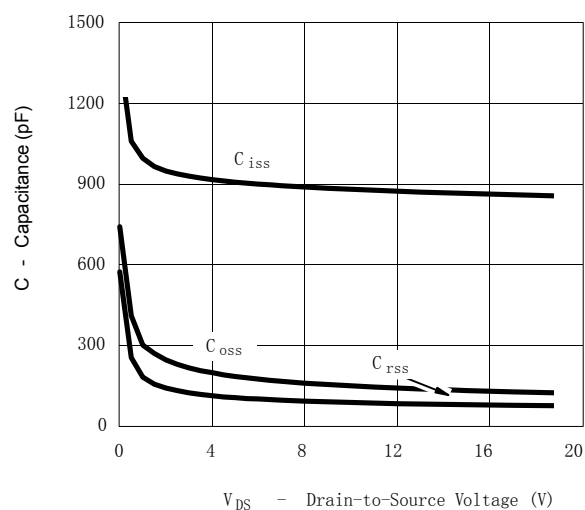
Transfer Characteristics



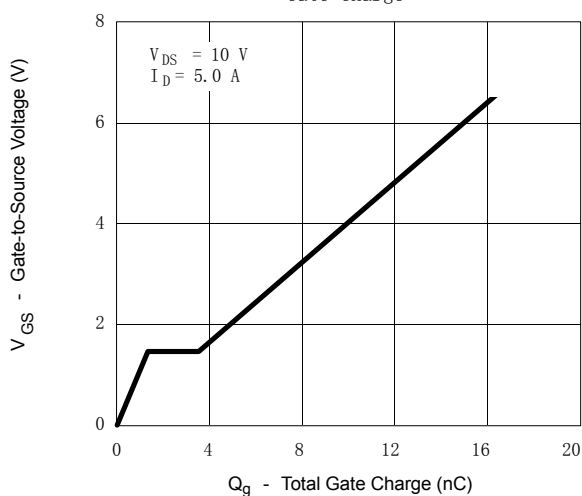
On-Resistance vs. Drain Current



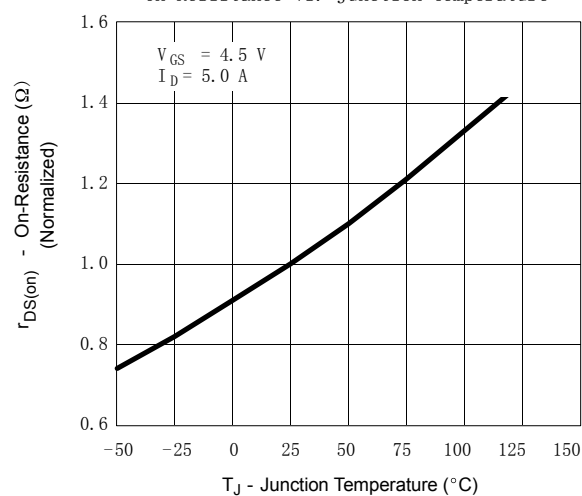
Capacitance



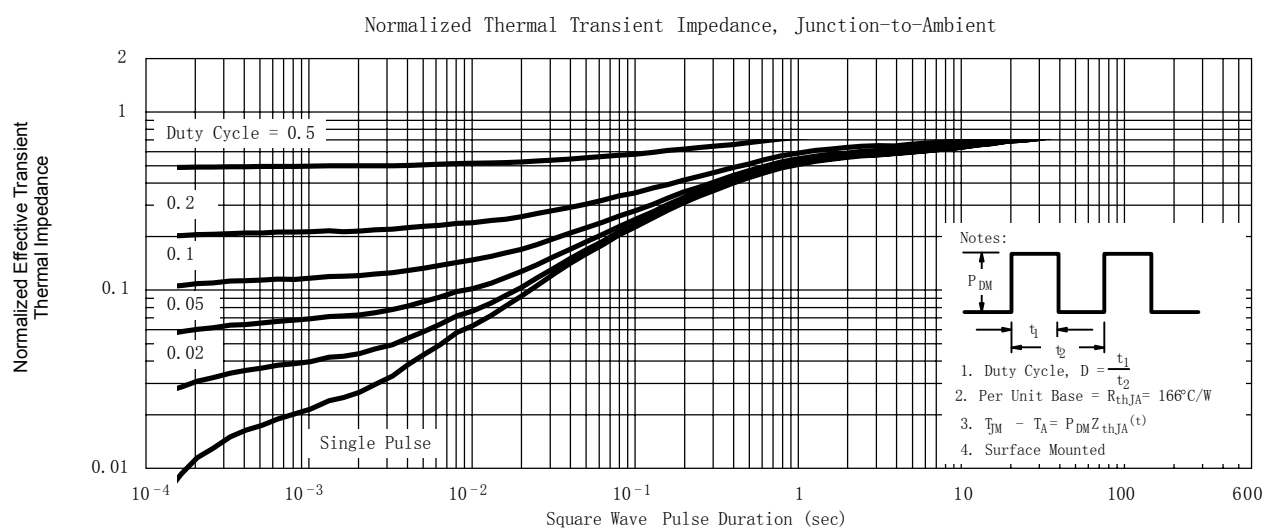
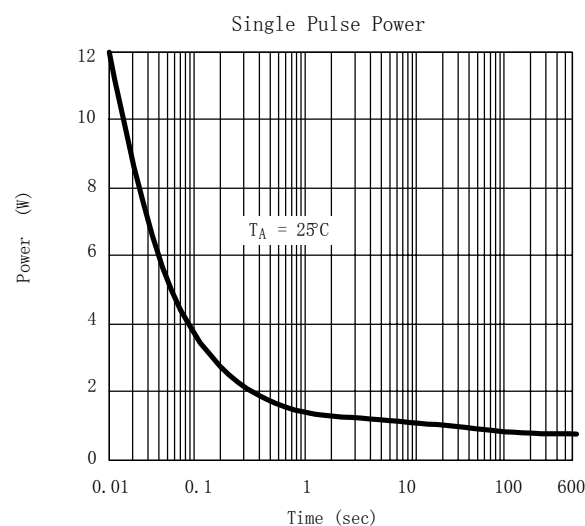
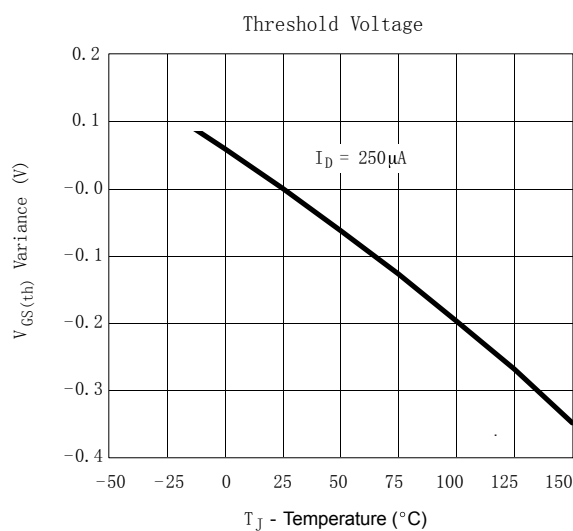
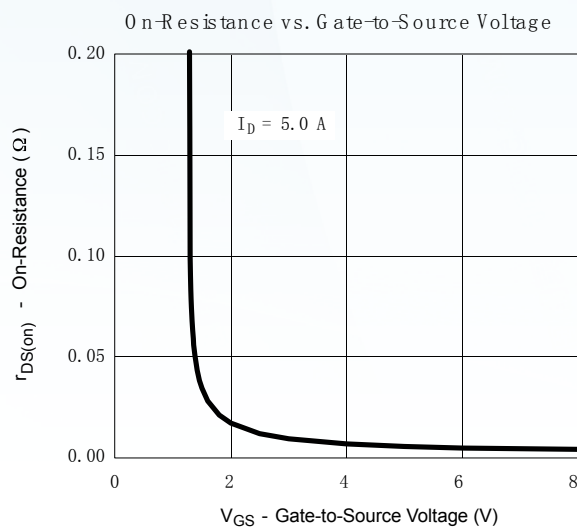
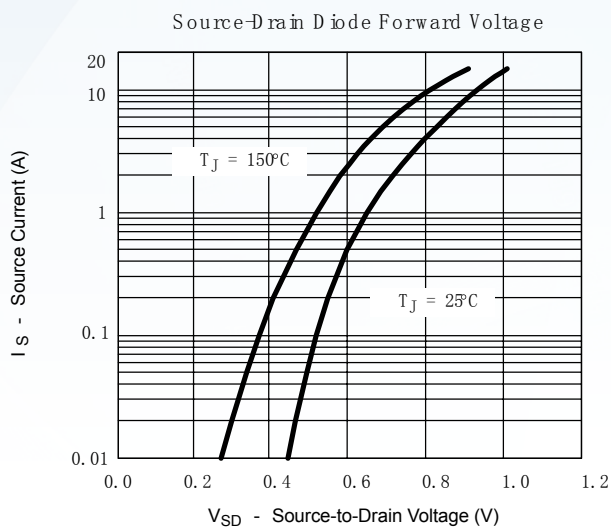
Gate Charge



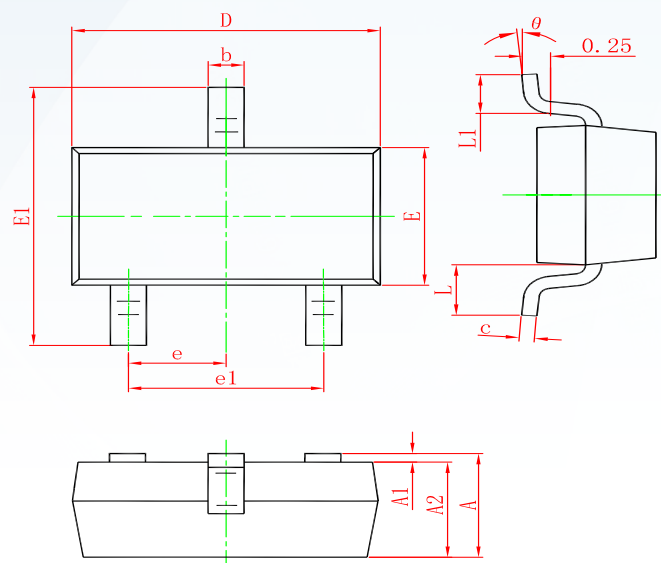
On-Resistance vs. Junction Temperature



■ Typical Characteristics

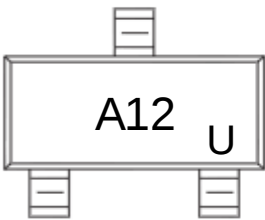


SOT-23 PACKAGE OUTLINE DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Marking



Ordering information

Order code	Package	Baseqty	Deliverymode
SI2312A	SOT-23	3000	Tape and reel

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